

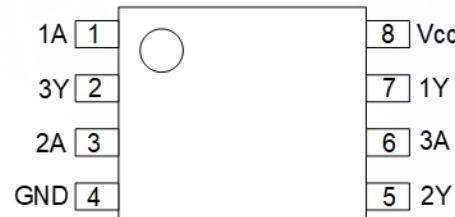
## Description

The 74LVC3G34 is a triple buffer gate with standard push-pull outputs. The device is designed for operation with a power supply range of 1.65V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output preventing damaging current backflow when the device is powered down.

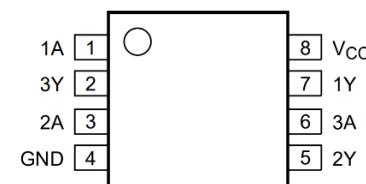
Each of the buffers performs the positive Boolean function:

$$Y = A$$

## Pin Assignments



SSOP-8



VSSOP-8

## Features

- Wide Supply Voltage Range from 1.65V to 5.5V
- $\pm 24\text{mA}$  Output Drive at 3.3V
- CMOS Low-Power Consumption
- $I_{OFF}$  Supports Partial Power Down Mode Operation
- Inputs Accept up to 5.5V
- ESD Protection Tested per JESD 22  
Exceeds 2000V Human Body Model (A114)  
Exceeds 1000V Charged Device Model (C101)
- Latch-Up Exceeds 100mA per JESD 78, Class I
- Range of Package Options
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- Halogen and Antimony Free. "Green" Device (Note 3)**
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](#) or your local Diodes representative.**

<https://www.diodes.com/quality/product-definitions/>

## Applications

- Voltage-level shifting
- General-purpose logic
- Power down signal isolation
- Wide array of products such as:
  - PCs, networking, notebooks, netbooks, PDAs
  - Computer peripherals, hard drives, CD/DVD ROM
  - TV, DVD, DVR, set top boxes
  - Cell phones, personal navigation/GPS
  - MP3 players, cameras, video recorders

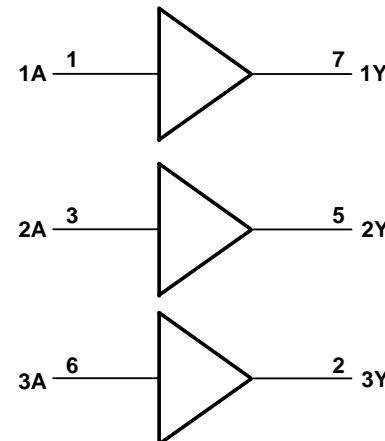
Notes:

- No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

## Pin Descriptions

Pin Name	Pin NO.	Description
1A	1	Data Input
3Y	2	Data Output
2A	3	Data Input
GND	4	Ground
2Y	5	Data Output
3A	6	Data Input
1Y	7	Data Output
Vcc	8	Supply Voltage

## Logic Diagram



## Function Table

Inputs	Output
A	Y
H	H
L	L

## Absolute Maximum Ratings (Notes 4, 5)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
Vcc	Supply Voltage Range	-0.5 to 6.5	V
Vi	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage Applied to Output in High Impedance or I <sub>OFF</sub> State	-0.5 to 6.5	V
Vo	Voltage Applied to Output in High or Low State	-0.5 to V <sub>cc</sub> + 0.5	V
I <sub>IK</sub>	Input Clamp Current Vi < 0	-50	mA
I <sub>OK</sub>	Output Clamp Current Vo < 0	-50	mA
I <sub>O</sub>	Continuous Output Current	±50	mA
I <sub>CC</sub> , I <sub>GND</sub>	Continuous Current Through V <sub>cc</sub> or GND	±100	mA
T <sub>J</sub>	Junction Temperature	+150	°C
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C

Notes:

4. Stresses beyond the absolute maximum can result in immediate failure or reduced reliability. These are stress values and device operation should be within recommended values.
5. Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum current could cause a condition exceeding the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range.

**Recommended Operating Conditions** (Note 6)

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	Operating Voltage	Operating	1.65	5.5	V
		Data Retention Only	1.5	—	V
V <sub>IH</sub>	High-Level Input Voltage	V <sub>CC</sub> = 1.65V to 1.95V	0.65 X V <sub>CC</sub>	—	V
		V <sub>CC</sub> = 2.3V to 2.7V	1.7	—	
		V <sub>CC</sub> = 3V to 3.6V	2	—	
		V <sub>CC</sub> = 4.5V to 5.5V	0.7 X V <sub>CC</sub>	—	
V <sub>IL</sub>	Low-Level Input Voltage	V <sub>CC</sub> = 1.65V to 1.95V	—	0.35 X V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3V to 2.7V	—	0.7	
		V <sub>CC</sub> = 3V to 3.6V	—	0.8	
		V <sub>CC</sub> = 4.5V to 5.5V	—	0.3 X V <sub>CC</sub>	
V <sub>I</sub>	Input Voltage	—	0	5.5	V
V <sub>O</sub>	Output Voltage	—	0	V <sub>CC</sub>	V
I <sub>OH</sub>	High-Level Output Current	V <sub>CC</sub> = 1.65V	—	-4	mA
		V <sub>CC</sub> = 2.3V	—	-8	
		V <sub>CC</sub> = 3V	—	-16	
			—	-24	
I <sub>OL</sub>	Low-Level Output Current	V <sub>CC</sub> = 4.5V	—	-32	mA
		V <sub>CC</sub> = 1.65V	—	4	
		V <sub>CC</sub> = 2.3V	—	8	
		V <sub>CC</sub> = 3V	—	16	
			—	24	
Δt/ΔV	Input Transition Rise or Fall Rate	V <sub>CC</sub> = 4.5V	—	32	ns/V
		V <sub>CC</sub> = 1.8V ± 0.15V, 2.5V ± 0.2V	—	20	
		V <sub>CC</sub> = 1.65V to 2.7V	—	10	
T <sub>A</sub>	Operating Free-Air Temperature	V <sub>CC</sub> = 2.7V to 5V	—	5	°C
		—	-40	+125	

Note: 6. Unused inputs should be held at V<sub>CC</sub> or Ground for device proper operation.

## Electrical Characteristics

Symbol	Parameter	Test Conditions	V <sub>cc</sub>	-40°C to +85°C		-40°C to +125°C		Unit
				Min	Max	Min	Max	
V <sub>OH</sub>	High-Level Output Voltage	I <sub>OH</sub> = -100µA	1.65V to 5.5V	V <sub>cc</sub> - 0.1	—	V <sub>cc</sub> - 0.1	—	V
		I <sub>OH</sub> = -4mA	1.65V	1.2	—	1.2	—	
		I <sub>OH</sub> = -8mA	2.3V	1.9	—	1.9	—	
		I <sub>OH</sub> = -16mA	3V	2.4	—	2.4	—	
		I <sub>OH</sub> = -24mA		2.3	—	2.3	—	
		I <sub>OH</sub> = -32mA	4.5V	3.8	—	3.8	—	
V <sub>OL</sub>	Low-Level Output Voltage	I <sub>OL</sub> = 100µA	1.65V to 5.5V	—	0.1	—	0.1	V
		I <sub>OL</sub> = 4mA	1.65V	—	0.45	—	0.45	
		I <sub>OL</sub> = 8mA	2.3V	—	0.3	—	0.3	
		I <sub>OL</sub> = 16mA	3V	—	0.4	—	0.4	
		I <sub>OL</sub> = 24mA		—	0.55	—	0.75	
		I <sub>OL</sub> = 32mA	4.5V	—	0.55	—	0.75	
I <sub>I</sub>	Input Current	V <sub>I</sub> = 5.5V or GND	0 to 5.5V	—	±5	—	±5	µA
I <sub>OFF</sub>	Power Down Leakage Current	V <sub>I</sub> or V <sub>O</sub> = 5.5V	0	—	±10	—	±10	µA
I <sub>CC</sub>	Supply Current	V <sub>I</sub> = 5.5V or GND, I <sub>O</sub> = 0	1.65V to 5.5V	—	10	—	10	µA
ΔI <sub>CC</sub>	Additional Supply Current	Input at V <sub>cc</sub> - 0.6V	3V to 5.5V	—	500	—	500	µA
C <sub>I</sub>	Input Capacitance	V <sub>I</sub> = V <sub>cc</sub> or GND	3.3V	—	3.5 (Typ)	—	—	pF

## Package Characteristics

Symbol	Parameter	Package	Test Conditions	Min	Typ	Max	Unit
θ <sub>JA</sub>	Thermal Resistance Junction-to-Ambient	SSOP-8	Note 7	—	130	—	°C/W
		VSSOP-8	Note 7	—	155	—	°C/W
θ <sub>JC</sub>	Thermal Resistance Junction-to-Case	SSOP-8	Note 7	—	36	—	°C/W
		VSSOP-8	Note 7	—	38	—	°C/W

Note: 7. Test condition: Device mounted on JEDEC 2s2p High-K board, FR-4 substrate PCB, 2oz copper with minimum recommended pad layout.

## Operating Characteristics (T<sub>A</sub> = +25°C, V<sub>cc</sub> = 3.3V)

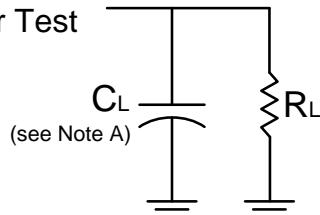
Symbol	Parameter	Test Conditions	V <sub>cc</sub> = 1.8V	V <sub>cc</sub> = 2.5V	V <sub>cc</sub> = 3.3V	V <sub>cc</sub> = 5V	Unit
			Typ	Typ	Typ	Typ	
C <sub>PD</sub>	Power Dissipation Capacitance	f = 10MHz, 1 Input Switching	19	19	19	21	pF

## Switching Characteristics

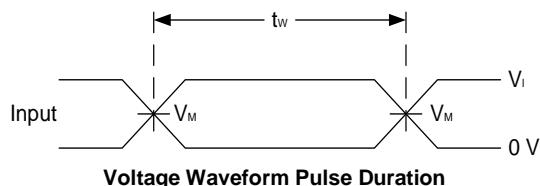
Figure 1

Parameter	From Input	To Output	V <sub>cc</sub>	T <sub>A</sub> = -40°C to +85°C		T <sub>A</sub> = -40°C to +125°C		Unit
				Min	Max	Min	Max	
t <sub>PD</sub>	A	Y	1.8V ± 0.15V	3.2	7.9	3.2	8.9	ns
			2.5V ± 0.2V	1.5	4.4	1.5	5.4	
			3.3V ± 0.3V	1.4	4.1	1.4	5.1	
			5.0V ± 0.5V	1.1	3.2	1.1	3.8	

## Parameter Measurement Information (Notes B, C, D)

 From Output  
 Under Test


V <sub>cc</sub>	Inputs		V <sub>M</sub>	C <sub>L</sub>	R <sub>L</sub>
	V <sub>I</sub>	t <sub>r</sub> /t <sub>f</sub>			
1.8V ± 0.15V	V <sub>cc</sub>	≤2ns	V <sub>cc</sub> / 2	30pF	1kΩ
2.5V ± 0.2V	V <sub>cc</sub>	≤2ns	V <sub>cc</sub> / 2	30pF	500Ω
3.3V ± 0.3V	3V	≤2.5ns	1.5V	50pF	500Ω
5.0V ± 0.5V	V <sub>cc</sub>	≤2.5ns	V <sub>cc</sub> / 2	50pF	500Ω



Voltage Waveform Pulse Duration

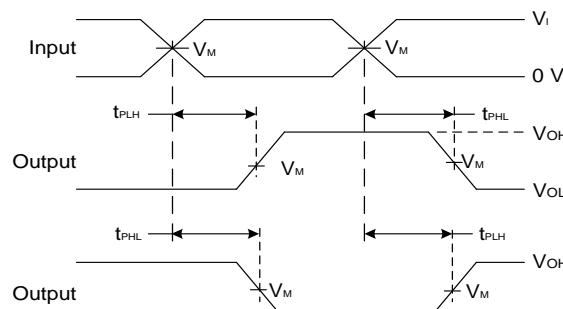
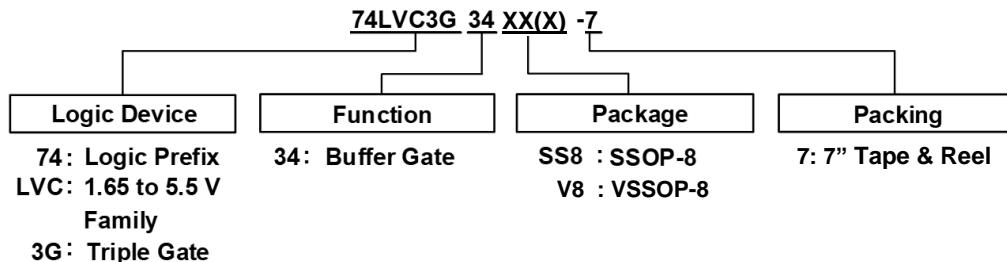

 Voltage Waveform Propagation Delay Time  
 Inverting and Noninverting Outputs

Figure 1. Load Circuit and Voltage Waveforms

Notes:

- A. Includes test lead and test apparatus capacitance.
- B. All pulses are supplied at pulse repetition rate ≤ 10MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>PD</sub>.

## Ordering Information



Part Number	Package Code	Package	Packing	
			Qty.	Carrier
74LVC3G34SS8-7	SS8	SSOP-8	3000	7" Tape and Reel (Note 8)
74LVC3G34V8-7	V8	VSSOP-8	3000	7" Tape and Reel (Note 8)

Note: 8. The taping orientation is located on our website at <http://www.diodes.com/package-outlines.html>.

## Marking Information

SSOP-8

(Top View)



**Y** : Year : 0 to 9  
**W** : Week : A to Z : 1 to 26 week;  
 a to z : 27 to 52 week; z represents  
 52 and 53 week  
**X** : Internal Code

Part Number	Package	Identification Code
74LVC3G34SS8-7	SSOP-8	S3G34

VSSOP-8

(Top View)



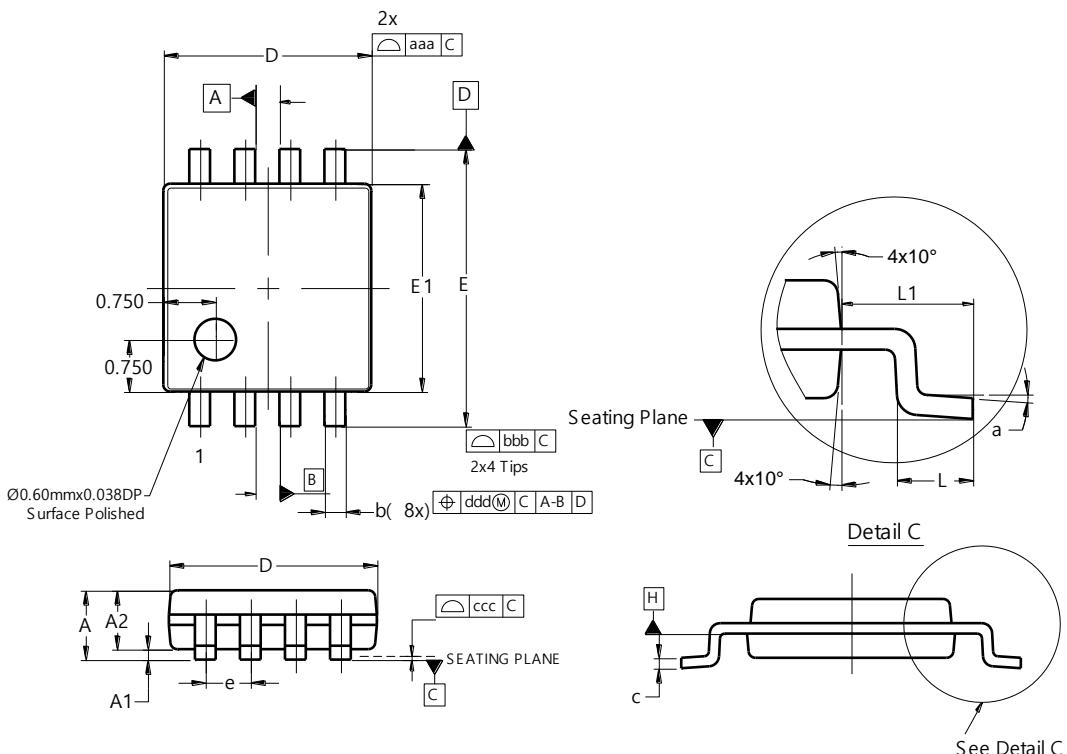
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Part Number	Package	Identification Code
74LVC3G34V8-7	VSSOP-8	V3G34

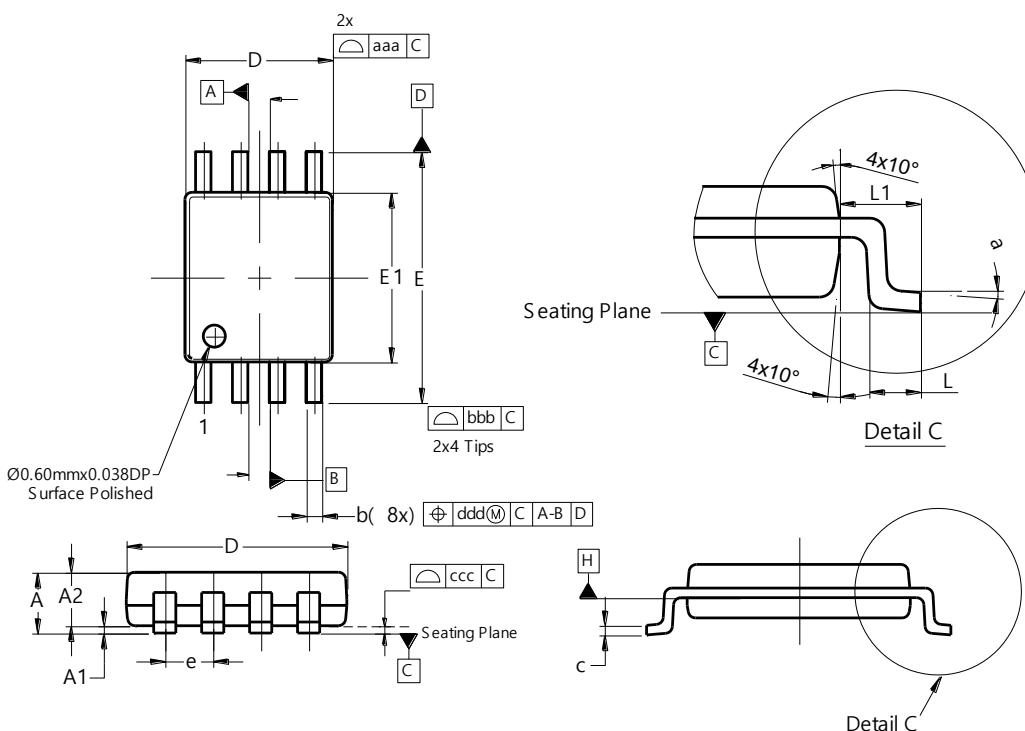
## Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**SSOP-8**



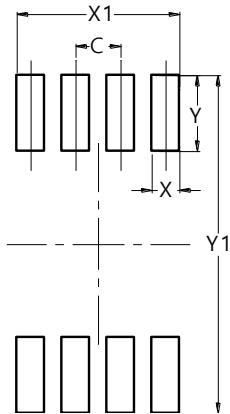
**VSSOP-8**



## Suggested Pad Layout

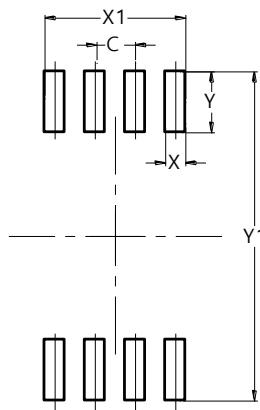
Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**SSOP-8**



Dimensions	Value (in mm)
C	0.650
X	0.400
X1	2.350
Y	1.100
Y1	4.900

**VSSOP-8**



Dimensions	Value (in mm)
C	0.500
X	0.250
X1	1.750
Y	0.750
Y1	4.050

## Mechanical Data

### SSOP-8

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Mate Tin Plated Leads, Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.0169 grams (Approximate)

### VSSOP-8

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Mate Tin Plated Leads, Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.011 grams (Approximate)

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